

60 V, N-channel Trench MOSFET 23 March 2016

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic level compatible
- Very fast switching
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM
- AEC-Q101 qualified

3. Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Quid	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	60	V
V _{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	-	0.8	А
Static characte	Static characteristics						
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 0.9 A; T _j = 25 °C		-	300	380	mΩ

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain	1 2 TO-236AB (SOT23)	G S 017aaa255

6. Ordering information

Table 3. Ordering information								
Type number	Package							
	Name	Description	Version					
PMV450ENEA	TO-236AB	plastic surface-mounted package; 3 leads	SOT23					

7. Marking

Table 4. Marking codes	
Type number	Marking code
	[1]
PMV450ENEA	DZ%

[1] % = placeholder for manufacturing site code

Limiting values 8.

Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

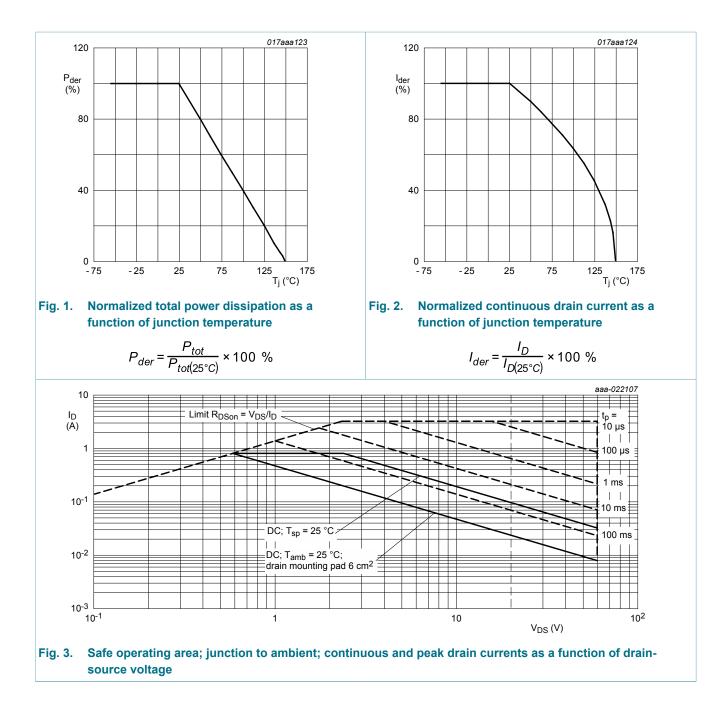
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	60	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	0.8	А
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	0.5	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	3.2	А
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$T_{j(init)}$ = 25 °C; I _D = 0.14 A; DUT in avalanche (unclamped)		-	4.2	mJ
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	323	mW
			[1]	-	466	mW
		T _{sp} = 25 °C		-	554	mW
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-dra	in diode		1			-
I _S	source current	T _{amb} = 25 °C	[1]	-	0.7	А
ESD Maxim	num rating					
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	2000	V

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm². Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard [1]

[2] footprint.

Measured between all pins. [3]

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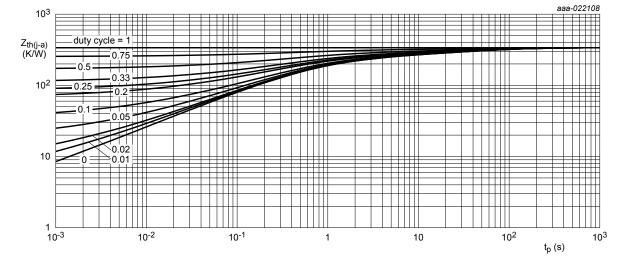


9. Thermal characteristics

Table 6. The	rmal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
fr	thermal resistance from junction to ambient	in free air	[1]	-	337	387	K/W
			[2]	-	233	268	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	57	66	K/W

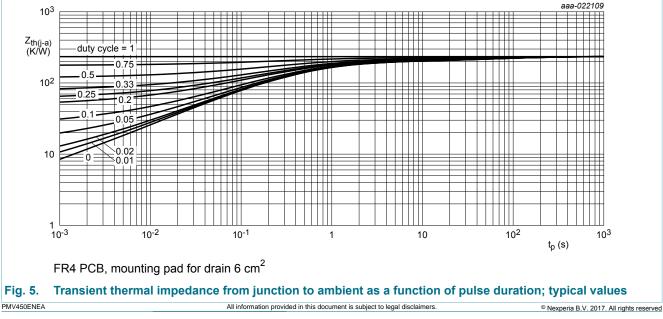
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



FR4 PCB, standard footprint





Product data sheet

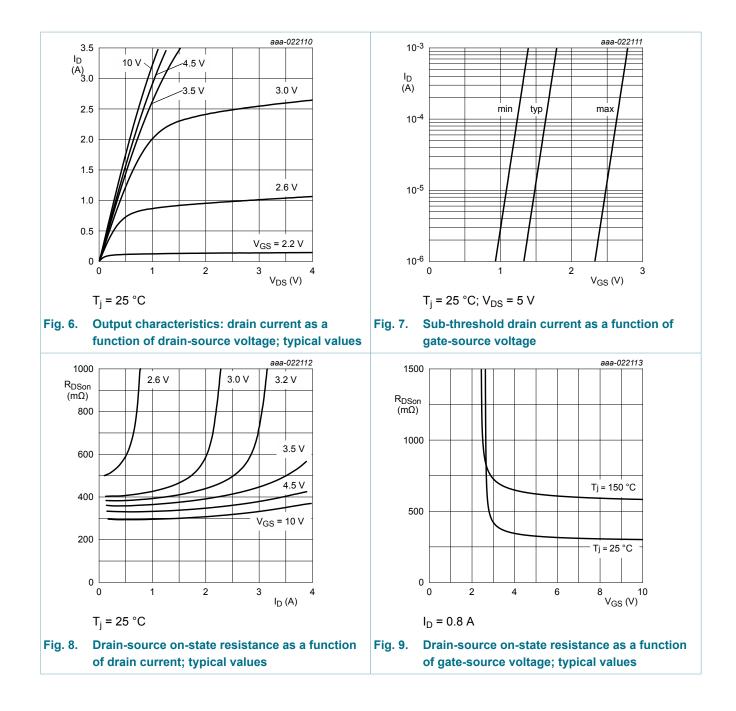
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	60	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = 250 μA; V _{DS} =V _{GS} ; T _j = 25 °C	1.3	1.7	2.7	V
I _{DSS}	drain leakage current	V_{DS} = 60 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	1	μA
		V_{GS} = -10 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-1	μA
20011	drain-source on-state	V_{GS} = 10 V; I _D = 0.9 A; T _j = 25 °C	-	300	380	mΩ
	resistance	V _{GS} = 10 V; I _D = 0.9 A; T _j = 150 °C	-	574	727	mΩ
		V _{GS} = 4.5 V; I _D = 0.8 A; T _j = 25 °C	-	332	440	mΩ
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 0.9 A; T _j = 25 °C	-	3.5	-	S
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	-	13	-	Ω
Dynamic ch	aracteristics	· · · ·	I			
Q _{G(tot)}	total gate charge	V_{DS} = 30 V; I _D = 0.9 A; V _{GS} = 10 V;	-	2.4	3.6	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.3	-	nC
Q _{GD}	gate-drain charge		-	0.4	-	nC
C _{iss}	input capacitance	V _{DS} = 30 V; f = 1 MHz; V _{GS} = 0 V;	-	101	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	10	-	pF
C _{rss}	reverse transfer capacitance		-	7	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 30 V; I _D = 0.9 A; V _{GS} = 10 V;	-	5	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	6	-	ns
t _{d(off)}	turn-off delay time	1	-	10	-	ns
t _f	fall time	1	-	3	-	ns
Source-drai	in diode	· · · · · ·	1			
V _{SD}	source-drain voltage	I _S = 0.7 A; V _{GS} = 0 V; T _i = 25 °C	-	0.8	1.2	V

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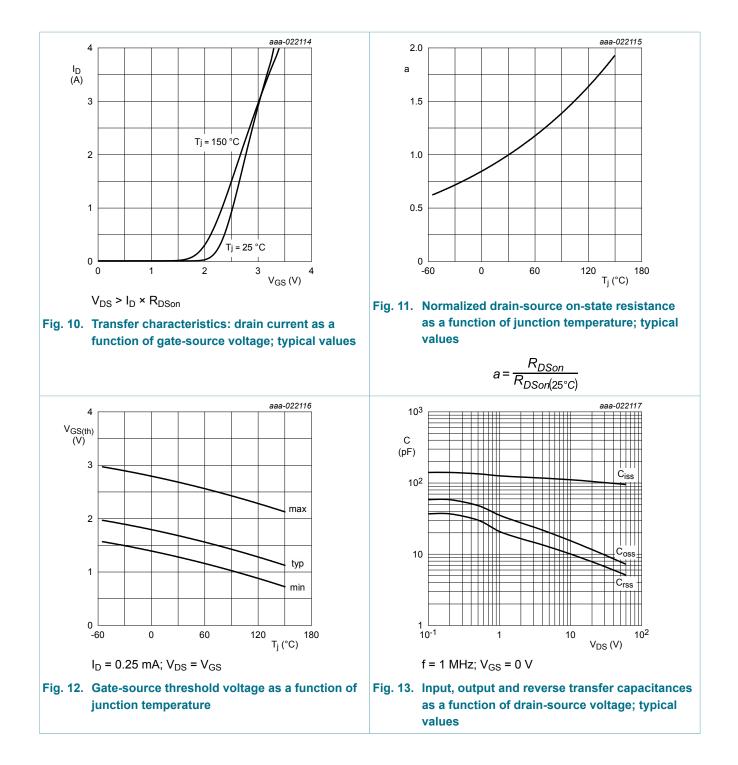


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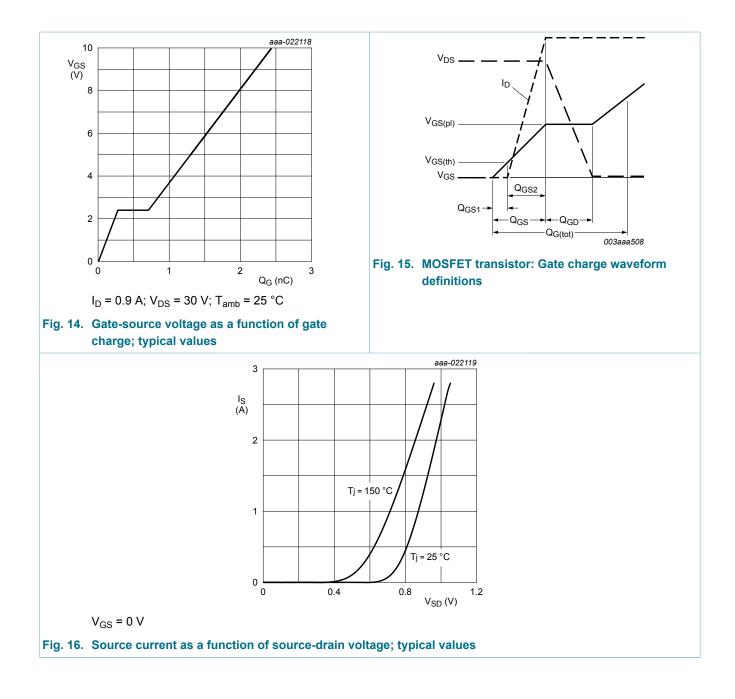


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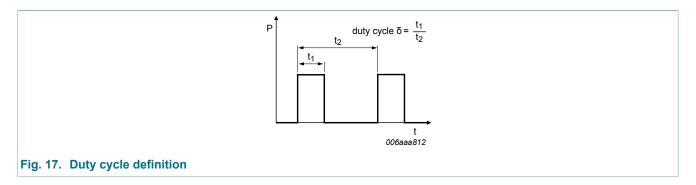
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11. Test information

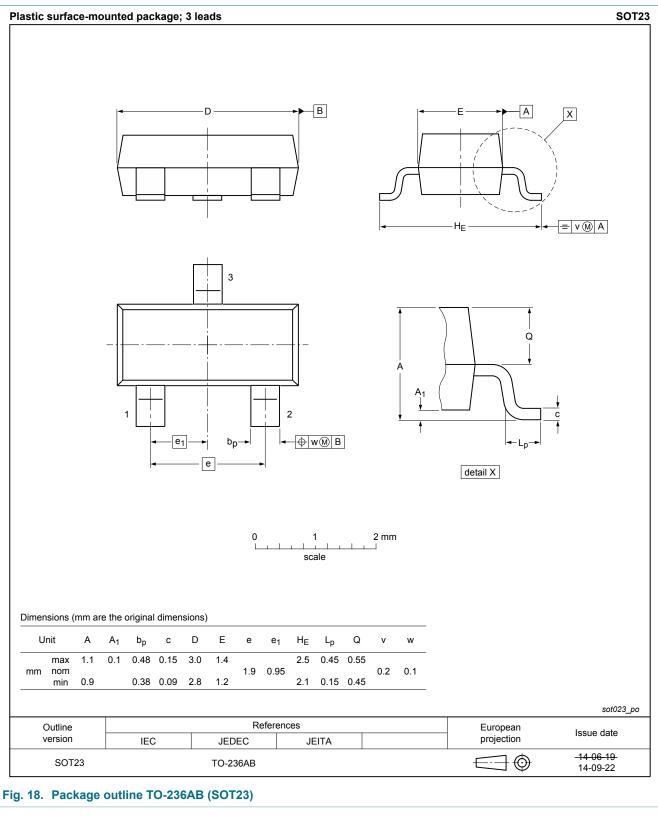


11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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12. Package outline



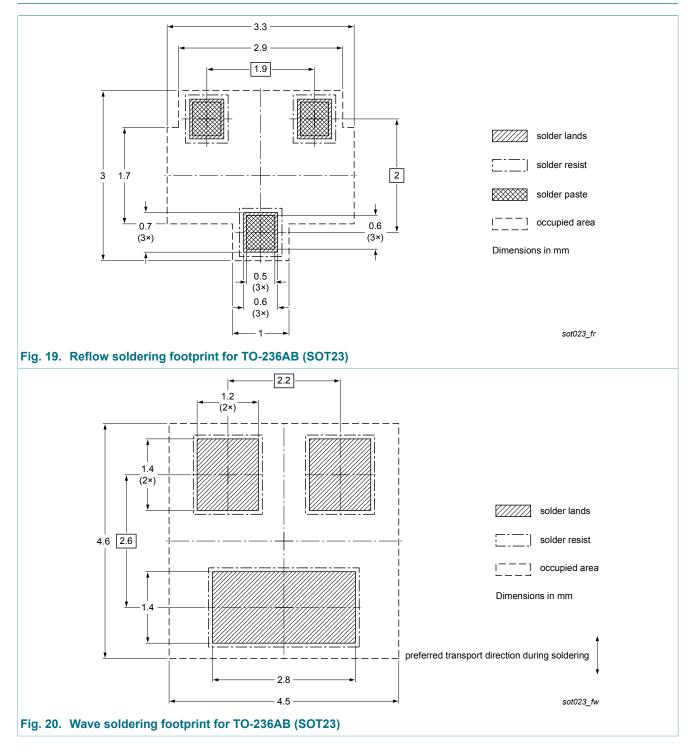
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13. Soldering



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14. Revision history

Table 8. Revision his	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMV450ENEA v.1	20160323	Product data sheet	-	-

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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